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#### **Inclosure Material:**

Metal all transistor

#### **Overall Length:**

0.360 inches all transistor and 0.390 inches all transistor

#### **Terminal Length:**

1.500 inches all transistor

# **Overall Diameter:**

0.370 inches all transistor

#### **Internal Configuration:**

Junction contact all transistor

# Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-11 all transistor

**Internal Junction Configuration:** 

#### Npn all transistor

**Component Function Relationship:** 

Matched

# **Component Name And Quantity:**

2 transistor

#### **Mounting Method:**

Terminal all transistor

# Terminal Circle Diameter:

0.190 inches all transistor and 0.210 inches all transistor

# **Features Provided:**

Hermetically sealed case

# Semiconductor Material:

Silicon all transistor

# Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-base, emitter open all transistor and 60.0 breakdown voltage, collector-to-emitter, base open all transistor and 28.0 collector to emitter voltage, dc all transistor

# **Current Rating Per Characteristic:**

4.50 milliamperes source cutoff current all transistor and 1.00 microamperes zero-gate-voltage source current preset all transistor

# **Power Rating Per Characteristic:**

1.0 watts small-signal input power, common-collector absolute all transistor

# Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction all transistor

#### **Terminal Type And Quantity:**

3 uninsulated wire lead all transistor

#### Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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